Measurements of the electron transmission rate of a full-size gating GEM in the absence of magnetic field

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Outline of My Talk

- 1. Brief Introduction
- 2. Measurement Technique
- 3. Measurement using an ⁵⁵Fe Source
- 4. Measurement using a UV Laser
- 5. Summary and Outlook
- 6. Brief Discussion

Introduction

- ILC TPC problem: Ion Back Flow -> Distortion of reconstructed tracks
- Expected Function of Gating GEM for ILC-TPC:

High Transparency for drift electrons at the OPEN state, and high blocking power for positive ions at the CLOSED state.



We measured the ELECTRON blocking power at the closed state as well the transmission rate at the open state using a full-size gating GEM in order to

- estimate the lower limit for the blocking power for positive ions, and
- study possibility for the application to TPCs, for which drift electrons needs to be efficiently prevented from entering the gas amplification region.

Measurement Technique



We measured the electron transmission (blocking) rate as a function of ΔV by observing the gas-amplified signals generated by an ⁵⁵Fe source or a UV laser.

Experimental Setup using an ⁵⁵Fe Source



Experimental Setup using an 55Fe Source



Chamber



• Used gas -> Ar : CF_4 : Iso- $C_4H_{10} = 95 : 3 : 2 [\%]$ (T2K gas)

Measurement using ⁵⁵Fe

We measured the signals with the normal and reversed drift fields for each ΔV .



Measurement using ⁵⁵Fe

Examples of the pulse height distribution ($\Delta V_{Gate-GEM} = +2.5V$)



Electron transmission rate vs. ΔV measured with ⁵⁵Fe



- The maximum transmission rate is about 86% at around $\Delta V = +3.5 V$.
- The transmission rate decreases slowly above +3.5 V.
- It decreases rapidly with increasing negative ΔV .
- The measurement is difficult below $\Delta V = -4.5 V$ because of small signals.

Experimental Setup using a Laser

We measured the electron transmission rate at negative ΔV using a laser.



Measurement using a Laser

Examples of the pulse height distribution



Measurement using a Laser (for Negatively High ΔV) 13

Example: $V_{Gating-GEM} = -14.5 V$



Measurement using a Laser (for Negatively High ΔV)



with Peak 2 at V_{Gating-GEM} = -0.5 V

Electron transmission rate vs. ΔV *Measure with the Laser and* ⁵⁵*Fe*



Electron transmission rate vs. ΔV (*Log Scale*)



• The transmission rate is measured to be as low as 3.3×10^{-4} at $\Delta V = -15.5$ V.

Summary

We have measured the electron transmission rate of a full-size gating GEM as a function of the potential difference (ΔV) for ΔV between -15.5 V and +20 V in the absence of axial magnetic field.

- The maximum transmission rate is about 86% at around $\Delta V = +3.5 V$.
- The transmission rate is measured to be as low as 3.3 × 10⁻⁴ at △V = −15.5 V. We can expect adequate ion blocking power for the ILC-TPC with the present gating GEM (see discussion below).
- Gating GEM may be applicable to TPCs for which drift electrons needs to be stopped. <u>A measurement in an axial magnetic field is necessary in order to prove it.</u>

<u>Future plan</u>

Direct measurements of the ion back-flow with/without a gating GEM.

Discussion

If we assume 2000 for the gas gain and define *F* as the ion back-flow rate of the amplifying GEMs, the number of positive ions entering the drift volume is expected to be about $0.66 \cdot F$ per drift electron with a gating GEM at $\Delta V = -15.5 V$.

It should be noted that the positive ions are thermal, i.e. the diffusion is small. Therefore it is (much) easier to block positive ions than electrons.

In addition, their motion is hardly affected by the presence of a magnetic field.

Consequently, the blocking power measured for electrons without magnetic field gives the lower limit for positive ions with a sufficient margin.

For example, if we assume (tentatively) 10% for *F* (with respect to the effective gain) the total ion back flow is expected to be (much) less than 0.07 per drift electron at $\Delta V = -15.5V$.

See also the next slide for the result of a simulation for the ion back-flow suppression.

Simulation of the ion suppression (ANSYS + Garfield) P. Gros et al., JINST 8 (2013) C11023



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FIN

Thank you for your attention.

Fitting of the pulse height distribution of ⁵⁵Fe signals

with 2 Gaussians and a polynomial (background)

 $\Delta V = + 2.5 V$



Normal - Reverse

